

- Ideal for European 868.95 MHz Transmitters
- Very Low Series Resistance
- Quartz Stability
- Complies with Directive 2002/95/EC (RoHS)



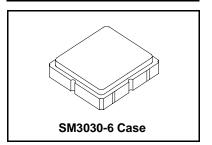
The RO3156E-3 is a true one-port, surface-acoustic-wave (SAW) resonator in a surface-mount ceramic case. It provides reliable, fundamental-mode, quartz frequency stabilization of fixed-frequency transmitters operating at 868.95 MHz. This SAW is designed specifically for remote-control and wireless security transmitters operating under ETSI EN 300 220.

Absolute Maximum Ratings

| Aboolato maximum Natingo | | | | |
|--|------------|-------|--|--|
| Rating | Value | Units | | |
| Input Power Level | 0 | dBm | | |
| DC Voltage | 12 | VDC | | |
| Operating Temperature Range | -40 to +85 | °C | | |
| Soldering Temperature, 10 seconds / 5 cycles maximum | +260 | °C | | |

RO3156E-3

868.95 MHz **SAW** Resonator



Electrical Characteristics

| Characteristic | | Sym | Notes | Minimum | Typical | Maximum | Units |
|-------------------------------|--------------------------------------|-------------------|------------|-------------------|----------------|---------|---------------------|
| Frequency, +25 °C | | f _C | 2,3,4,5 | 868.880 | | 869.020 | MHz |
| Tolerance from 868.95 MHz | RO3156E | Δf_{C} | 2,3,4,5 | | | ±70 | kHz |
| Insertion Loss | | IL | 2,5,6 | | 1.2 | 2.0 | dB |
| Quality Factor | Unloaded Q | Q _U | 5,6,7 | | 6700 | | |
| | 50 $Ω$ Loaded Q | Q_L | | | 800 | | |
| Temperature Stability | Turnover Temperature | T _O | | 10 | 25 | 40 | °C |
| | Turnover Frequency | f _O | 6,7,8 | | f _C | | kHz |
| | Frequency Temperature Coefficient | FTC | | | 0.032 | | ppm/°C ² |
| Frequency Aging | Absolute Value during the First Year | fA | 1 | | <±10 | | ppm/yr |
| DC Insulation Resistance bet | ween Any Two Terminals | | 5 | 1.0 | | | MΩ |
| RF Equivalent RLC Model | Motional Resistance | R_{M} | | | 14.1 | | Ω |
| | Motional Inductance | L_M | 5, 6, 7, 9 | | 17.2 | | μH |
| | Motional Capacitance | C _M | | | 2.0 | | fF |
| | Shunt Static Capacitance | Co | 5, 6, 9 | | 2.3 | | pF |
| Test Fixture Shunt Inductance | 9 | L _{TEST} | 2, 7 | | 14.6 | | nH |
| Lid Symbolization | | | | | 949 // YWWS | 3 | |
| Standard Reel Quantity | Reel Size 7 Inch | | 10 | 500 Pieces / Reel | | | |
| | Reel Size 13 Inch | 10 3000 P | | 3000 Pied | ces / Reel | | |

CAUTION: Electrostatic Sensitive Device. Observe precautions for handling.

- Frequency aging is the change in $\rm f_{\rm C}$ with time and is specified at +65 $^{\circ}{\rm C}$ or less. Aging may exceed the specification for prolonged temperatures above +65 $^{\circ}$ C. Typically, aging is greatest the first year after manufacture, decreasing in subse-
- quent years.

 The center frequency, f_C, is measured at the minimum insertion loss point, IL_{MIN}, with the resonator in the 50 Ω test system (VSWR \leq 1.2:1). The shunt inductance, L_{TEST}, is tuned for parallel resonance with C_O at f_C. Typically,
- foscillator or ftransmitter is approximately equal to the resonator fc. One or more of the following United States patents apply: 4,454,488 and 4,616,197. 3.
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer. Unless noted otherwise, case temperature $T_C = +25$ °C±2 °C.
- The design, manufacturing process, and specifications of this device are subject to change without notice.

- Derived mathematically from one or more of the following directly measured parameters: f_{C} , IL, 3 dB bandwidth, f_{C} versus T_{C} , and C_{O} . Turnover temperature, T_{O} , is the temperature of maximum (or turnover) frequency, f_{O} . The nominal frequency at any case temperature, T_{C} , may be 8. calculated from: $f = f_O [1 - FTC (T_O - T_C)^2]$. Typically oscillator T_O is approximately equal to the specified resonator To.
- This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_{O} is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF. Transducer parallel capacitance can by calculated as: $C_P \approx C_O - 0.05 \text{ pF}.$
- Tape and Reel Standard for ANSI / EIA 481.

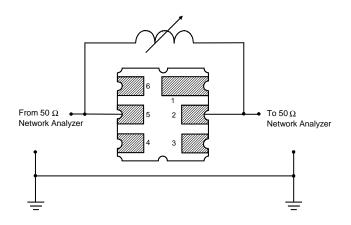
Electrical Connections

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.

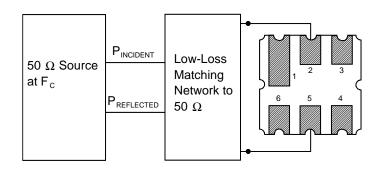
| Pin | Connection | | |
|-----|------------|--|--|
| 1 | NC | | |
| 2 | Terminal | | |
| 3 | NC | | |
| 4 | NC | | |
| 5 | Terminal | | |
| 6 | NC | | |

Typical Test Circuit

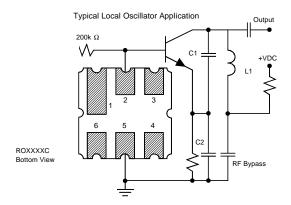
The test circuit inductor, L_{TEST} , is tuned to resonate with the static capacitance, C_O , at F_C .



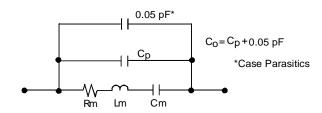
Power Test



Typical Application Circuits

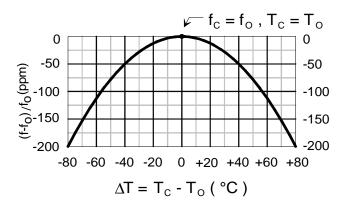


Equivalent LC Model



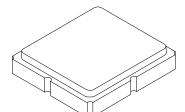
Temperature Characteristics

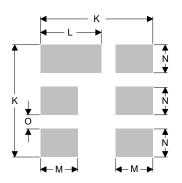
The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.



SM3030-6 Case

6-Terminal Ceramic Surface-Mount Case 3.0 X 3.0 mm Nominal Footprint





PCB Footprint Top View

Case and PCB Footprint Dimensions

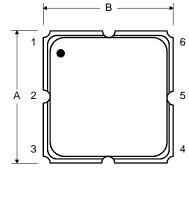
| Dimension | mm | | | Inches | | | |
|-------------|------|------|------|--------|-------|-------|--|
| Difficusion | Min | Nom | Max | Min | Nom | Max | |
| Α | 2.87 | 3.00 | 3.13 | 0.113 | 0.118 | 0.123 | |
| В | 2.87 | 3.00 | 3.13 | 0.113 | 0.118 | 0.123 | |
| С | 1.12 | 1.25 | 1.38 | 0.044 | 0.049 | 0.054 | |
| D | 0.77 | 0.90 | 1.03 | 0.030 | 0.035 | 0.040 | |
| E | 2.67 | 2.80 | 2.93 | 0.105 | 0.110 | 0.115 | |
| F | 1.47 | 1.60 | 1.73 | 0.058 | 0.063 | 0.068 | |
| G | 0.72 | 0.85 | 0.98 | 0.028 | 0.033 | 0.038 | |
| Н | 1.37 | 1.50 | 1.63 | 0.054 | 0.059 | 0.064 | |
| I | 0.47 | 0.60 | 0.73 | 0.019 | 0.024 | 0.029 | |
| J | 1.17 | 1.30 | 1.43 | 0.046 | 0.051 | 0.056 | |
| K | | 3.20 | | | 0.126 | | |
| L | | 1.70 | | | 0.067 | | |
| М | | 1.05 | | | 0.041 | | |
| N | | 0.81 | | | 0.032 | | |
| 0 | | 0.38 | | | 0.015 | | |

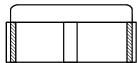
Case Materials

← D →

| Materials | | | |
|-----------------------|--|--|--|
| Solder Pad Plating | 0.3 to 1.0 μm Gold over 1.27 to 8.89 μm Nickel | | |
| Lid Plating | 2.0 to 3.0 µm Nickel | | |
| Body | Al ₂ O ₃ Ceramic | | |
| Pb Free | | | |

Top View





Bottom View

